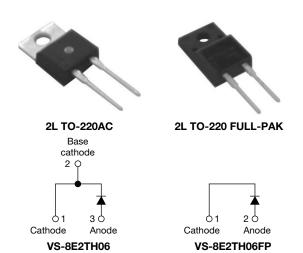
Vishay Semiconductors

RoHS

COMPLIANT

HALOGEN FREE

Hyperfast Rectifier, 8 A FRED Pt®



PRODUCT SUMMARY					
Package	2L TO-220AC, 2L TO-220 FP				
I _{F(AV)}	8 A				
V _R	600 V				
V _F at I _F	2.5 V				
t _{rr} (typ.)	17 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- \bullet Hyperfast recovery time, reduced Q_{rr} and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- True 2 pin package
- Low forward voltage drop
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- Compliant to RoHS directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- · Designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time, and soft recovery.

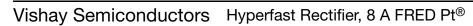
The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the ac-to-dc section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V_{RRM}		600	V		
Average rectified forward current		T _C = 133 °C	8			
FULL-PAK	I _{F(AV)}	T _C = 78 °C	O			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	70	Α		
Peak repetitive forward current	I _{FM}		16			
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-		
Forward voltage	V	I _F = 8 A	-	2.1	2.5		
	V _F	I _F = 8 A, T _J = 150 °C	-	1.6	1.9		
Deverse leeke se euwent	,	V _R = V _R rated	-	0.2	35		
Reverse leakage current I _R		T _J = 150 °C, V _R = V _R rated	-	50	350	μA	
Junction capacitance	C _T	V _R = 600 V	-	6	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	





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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		17	23	
		$I_F = 8.0 \text{ A, } dI_F/dt =$	$I_F = 8.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		22	25	
		T _J = 25 °C	$I_F = 8 A$ $dI_F/dt = 200 A/\mu s$	i	22	-	
Reverse recovery time	t _{rr}		$V_{R} = 390 \text{ V}$	-	43	-	ns
		T _J = 125 °C	$I_F = 8 \text{ A}$ $dI_F/dt = 600 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	33	-	
	IRRM	T _J = 25 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 390 V	-	3.1	-	
Peak recovery current		T _J = 125 °C		-	5.2	-	A
Peak recovery current			I _F = 8 A dI _F /dt = 600 A/μs V _R = 390 V	-	13	-	Α
		T _J = 25 °C	I _F = 8 A	-	32	-	
Reverse recovery charge	Q _{rr}	T _J = 125 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	120	-	nC
			I _F = 8 A dI _F /dt = 600 A/μs V _R = 390 V	-	230	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C	
Thermal resistance,	D		-	2	2.4		
junction to case FULL-PAK	R_{thJC}		-	5	5.5		
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Weight			-	2	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Madinada		Case style TO-220	8E2TH06				
Marking device		Case style TO-220 FULL-PAK		8E2TI	H06FP		





Hyperfast Rectifier, 8 A FRED Pt® Vishay Semiconductors

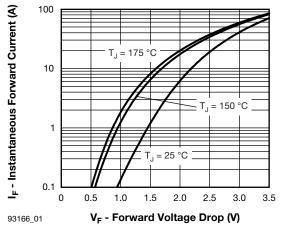


Fig. 1 - Typical Forward Voltage Drop Characteristics

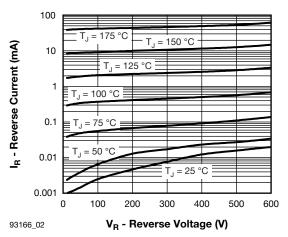


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

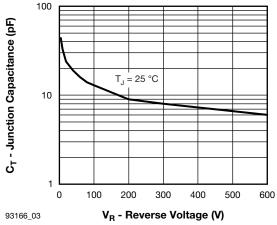


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

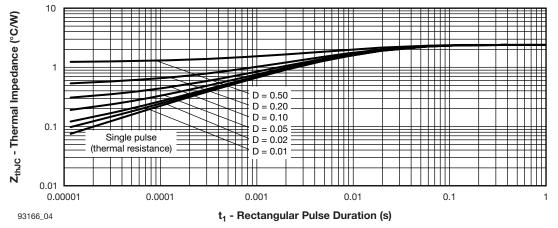


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (TO-220)

Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®



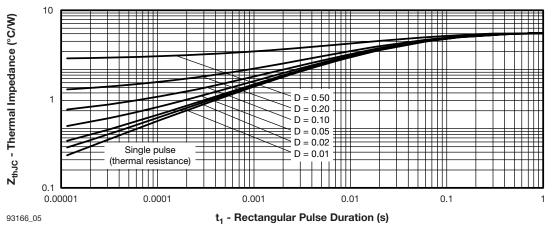


Fig. 5 - Maximum Thermal Impedance Z_{thJC} Characteristics (FULL-PAK)

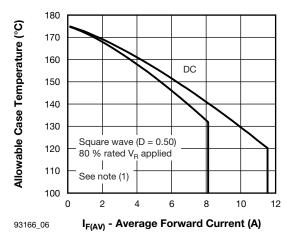


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current (TO-220)

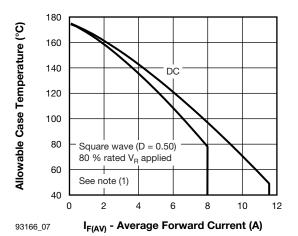


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

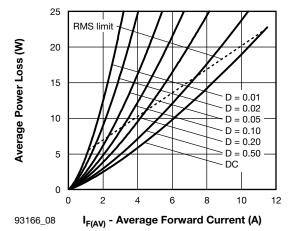


Fig. 8 - Forward Power Loss Characteristics

Note

(1) Formula used: $T_C = T_J$ - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at ($I_{F(AV)}$ /D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = Rated V_R

Hyperfast Rectifier, 8 A FRED Pt® Vishay Semiconductors

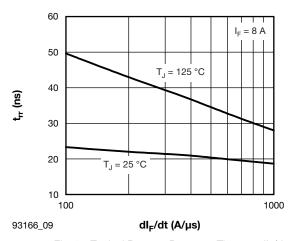


Fig. 9 - Typical Reverse Recovery Time vs. dI_F/dt

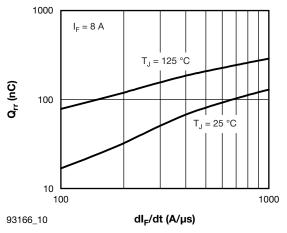


Fig. 10 - Typical Stored Charge vs. dl_F/dt

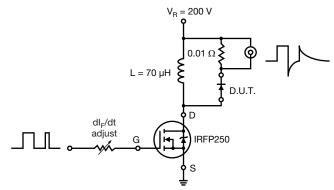
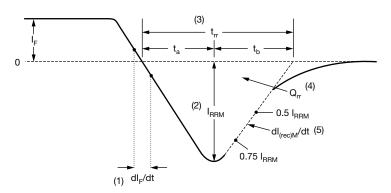


Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 12 - Reverse Recovery Waveform and Definitions

Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®

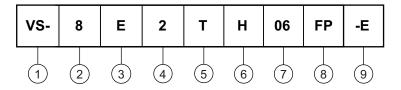


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ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product suffix
- **2** Current rating (8 = 8 A)
- 3 Circuit configuration:
 - E = Single diode
- 4 2 = True 2 pin package
- **5** T = TO-220
- 6 H = Hyperfast recovery time
- 7 Voltage code (06 = 600 V)
- 8 • None = TO-220
 - FP = FULL-PAK
- 9 Environmental digit:
 - -E = RoHS compliant and terminations lead (Pb)-free
 - -M = Halogen-free, RoHS compliant and terminations lead (Pb)-free

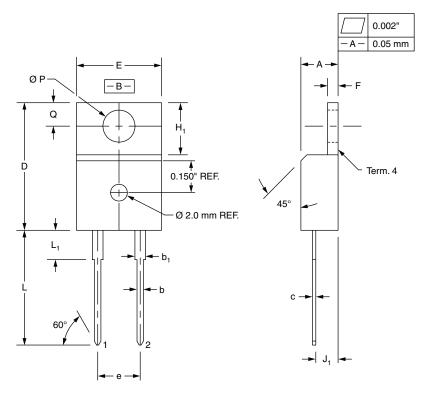
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-8E2TH06-E	50	1000	Antistatic plastic tubes			
VS-8E2TH06-M	50	1000	Antistatic plastic tubes			
VS-8E2TH06FP-E	50	1000	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-220AC	www.vishay.com/doc?95259			
Dimensions	TO-220 FULL-PAK	www.vishay.com/doc?95260			
Part marking information	TO-220AC	www.vishay.com/doc?95391			
	TO-220 FULL-PAK	www.vishay.com/doc?95392			
Packaging information		www.vishay.com/doc?95388			

Vishay High Power Products

True 2 Pin TO-220

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES
STMBOL	MIN.	MAX.	MIN.	MAX.
A	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
E	10.04	10.41	0.395	0.410
е	5.08	BSC	0.200 BSC	
F	1.22	1.37	0.048	0.054
H ₁	5.97	6.47	0.235	0.255
J ₁	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L ₁ ⁽¹⁾	3.31	3.81	0.130	0.150
ØP	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

Notes

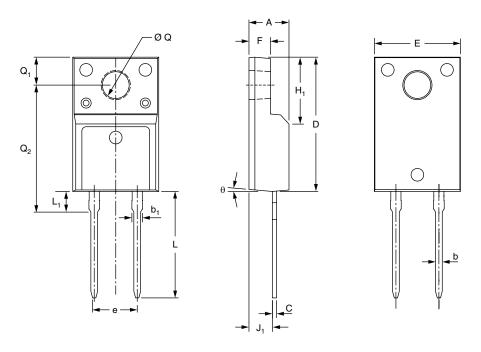
- (1) Lead dimension and finish uncontrolled in L₁
- These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87
- Controling dimension: Inch



Vishay High Power Products

True 2 Pin TO-220 FULL-PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	METERS	INCH	ES
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
е	5.08 typical		0.200 ty	pical
F	2.34	2.74	0.092	0.107
H ₁	6.50	6.90	0.256	0.272
J ₁	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L ₁	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q ₁	3.10	3.50	0.122	0.138
Q ₂	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°



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